NSN 5961-01-008-8918

Thyristor Semiconductor Device - Page 1 of 1



view Online at https://aerobasegroup.com/nsn/5961-01-006-8916
Inclosure Material:
Metal
Overall Length:
0.505 inches
Mounting Facility Quantity:
1
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
0.558 inches
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
500.0 breakover voltage, dc
Current Rating Per Characteristic:
225.00 amperes forward current, average absolute
Maximum Operating Tempurature Per Measurement Point:
110.0 degrees celsius junction
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 2 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0